Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-823-9527

	aterial:
Metal	
Overall Len	-
	70 inches and 0.210 inches
Terminal Le	
0.500 inches	
Overall Diar	neter:
	09 inches and 0.230 inches
	onic Device Engineering Council/jedec/case Outline Designation:
To-71	
Component	Name And Quantity:
2 transistor	
Mounting M	lethod:
Terminal	
Terminal Ci	rcle Diameter:
0.100 inches	
Features Pr	ovided:
Hermetically	sealed case
Semicondu	ctor Material:
Silicon all tra	ansistor
Voltage Rat	ing In Volts Per Characteristic:
50.0 breakd	own voltage, gate-to-source, with all other terminals short-circuited to source all transistor and 3.0 gate to source cutoff voltage
all transistor	
Current Rat	ing Per Characteristic:
10.00 millian	nperes zero-gate-voltage drain current all transistor
Terminal Ty	pe And Quantity:
6 uninsulated	d wire lead
Shelf Life:	
N/a	
Unit Of Mea	sure:
Demilitariza	tion:
No	
Fiig:	
A110a0	